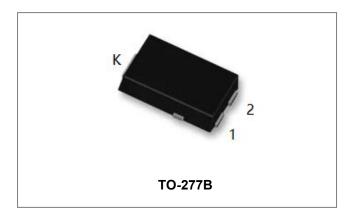


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RoHS HF

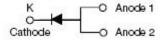
# ST15200S SCHOTTKY RECTIFIER



### Features

- 150°C TJ operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- "-A" is an AEC-Q101 qualified device
- Terminals finish: 100% Pure Tin
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	200	V
Average Forward Current (Note 1)	IF(AV)	50% duty cycle $@T_A = 25^{\circ}C$ rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, $T_J$ = 25 °C	200	А

Note: 1. Mounted on 30 mm x 30 mm pad areas aluminum PCB

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.83	1.34	V
	V <sub>F2</sub>	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.77	0.80	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 25 °C	0.11	0.6	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>L</sub> = 125 °C	0.5	45	mA

\* Pulse width < 300  $\mu$ s, duty cycle < 2%

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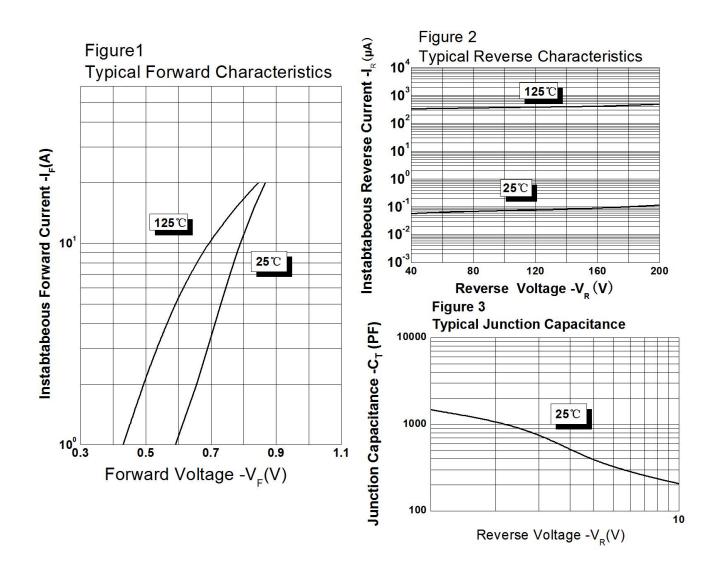
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### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0JC</sub>	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	R <sub>0JA</sub>		70	°C/W
Approximate Weight	wt	-	0.08	g

### **Ratings and Characteristics Curves**



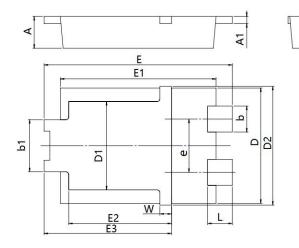
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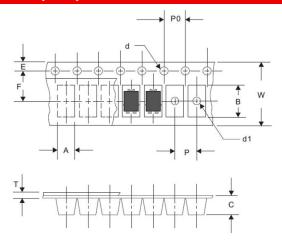
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### **Mechanical Dimensions TO-277B**



SYMBOL	Millimeters		Inches	
STNIDUL	Min.	Max.	Min.	Max.
A	0.95	1.25	0.037	0.049
A1	0.20	0.30	0.008	0.012
b	0.85	0.95	0.033	0.037
b1	1.70	1.90	0.067	0.075
D	3.88	4.08	0.153	0.161
D1	2.90	3.20	0.114	0.126
D2	4.25	-	0.167	-
е	1.74	1.94	0.069	0.076
E	6.30	6.70	0.248	0.264
E1	5.28	5.48	0.208	0.216
E2	3.40	3.70	0.134	0.146
E3	4.20	4.60	0.165	0.181
L	0.65	1.05	0.025	0.041
W	0.25	0.55	0.010	0.022

### **Carrier Tape Specification TO-277B**



### **Ordering Information**

Device	Package	Shipping	
ST15200S	TO-277B(Pb-Free)	5000pcs/ reel	
ST15200STR	TO-277B(Pb-Free)	5000pcs/ reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

SYMBOL	Millimeters		
	Min.	Max.	
A	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

T 15

200

SSG

YΥ

L

WW

S

### **Marking Diagram**

T15200S XXXXX

### Where XXXXX is YYWWL

- = Device Type
  - = Forward Current (15A)
- = Reverse Voltage (200V)
- = Package type
- = SSG
- = Year = Week
- = Vveek = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

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